











SN54AHC244, SN74AHC244

SCLS226K-OCTOBER 1995-REVISED JULY 2014

SNx4AHC244 Octal Buffers/Drivers With 3-State Outputs

Features

- Operating Range 2-V to 5.5-V V_{CC}
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- On Products Compliant to MIL-PRF-38535, All Parameters Are Tested Unless Otherwise Noted. On All Other Products, Production Processing Does Not Necessarily Include Testing of All Parameters.

2 Applications

- **Network Switches**
- Power Infrastructures
- PCs and Notebooks
- Wearable Health and Fitness Devices
- Tests and Measurements

3 Description

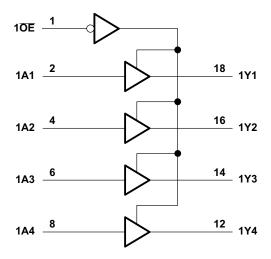
These octal buffers and drivers are designed specifically to improve the performance and density of 3-state memory-address drivers, clock drivers, and bus-oriented receivers and transmitters.

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
	SSOP (20)	7.20 mm × 5.30 mm		
	SOIC (20)	12.80 mm × 7.50 mm		
SNx4AHC244	PDIP (20)	24.33 mm × 6.35 mm		
	TSSOP (20)	12.60 mm × 5.30 mm		
	VQFN (20)	4.50 mm × 3.50 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Schematic



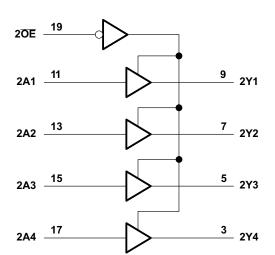




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5 Revision History

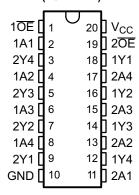
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

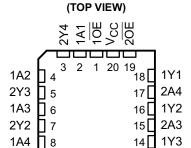
С	hanges from Revision J (July 2003) to Revision K	Page
•	Updated document to new TI data sheet format	
•	Removed Ordering Information table.	1
•	Added Military Disclaimer to Features list.	1
•	Added Applications.	1
•	Added Pin Functions table	3
•	Added Handling Ratings table	4
•	Changed MAX ambient temperature in Recommended Operating Conditions table	4
•	Added Thermal Information table.	5
•	Added Typical Characteristics.	7



6 Pin Configuration and Functions

SN54AHC244 . . . J OR W PACKAGE SN74AHC244 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)





9 10 11 12 13

2Y1 GND 2A1 1Y4 2A2

SN54AHC244 . . . FK PACKAGE

Pin Functions

PIN		1/0	DESCRIPTION
NO.	NAME	1/0	DESCRIPTION
1	1 OE	I	Output Enable 1
2	1A1	I	1A1 Input
3	2Y4	0	2Y4 Output
4	1A2	I	1A2 Input
5	2Y3	0	2Y3 Output
6	1A3	I	1A3 Input
7	2Y2	0	2Y2 Output
8	1A4	I	1A4 Input
9	2Y1	0	2Y1 Output
10	GND	_	Ground pin
11	2A1	I	2A1 Input
12	1Y4	0	1Y4 Output
13	2A2	I	2A2 Input
14	1Y3	0	1Y3 Output
15	2A3	I	2A3 Input
16	1Y2	0	1Y2 Output
17	2A4	1	2A4 Input
18	1Y1	0	1Y1 Output
19	2 OE	I	Output Enable 2
20	VCC		Power Pin



Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V_{CC}	Supply voltage range		-0.5	7	V
V_{I}	Input voltage range (2)		-0.5	7	V
Vo	Output voltage range ⁽³⁾		-0.5	$V_{CC} + 0.5$	V
I _{IK}	Input clamp current	V _I < 0		-20	mA
I _{OK}	Output clamp current	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		±25	mA
	Continuous current through each V _{CC} or GND			±50	mA

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 Handling Ratings

			MIN	MAX	UNIT
T _{stg}	Storage temperature rang	e	- 65	150	°C
V	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins (1)	0	1500	\/
V _(ESD)		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins (2)	0	2000	V

JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			SN54AH	SN54AHC244		C244	UNIT	
			MIN	MAX	MIN	MAX	UNII	
V _{CC}	Supply voltage		2	5.5	2	5.5	V	
		V _{CC} = 2 V	1.5		1.5			
V_{IH}	High-level input voltage	V _{CC} = 3 V	2.1		2.1		V	
		V _{CC} = 5.5 V	3.85		3.85			
		V _{CC} = 2 V		0.5		0.5		
V_{IL}	Low level input voltage	$V_{CC} = 3 V$		0.9		0.9	V	
		V _{CC} = 5.5 V		1.65		1.65		
V_{I}	Input voltage		0	5.5	0	5.5	V	
Vo	Output voltage		0	V _{CC}	0	V _{CC}	V	
		V _{CC} = 2 V		-50		-50	μA	
I _{OH}	High-level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		-4		-4		
		$V_{CC} = 5 V \pm 0.5 V$		-8		-8	mA	
		V _{CC} = 2 V		50		50	μΑ	
I_{OL}	Low level output current	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		4		4	A	
		$V_{CC} = 5 V \pm 0.5 V$		8		8	mA	
Δt/Δν		$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		100		100	ns/V	
ΔυΔν	Input transition rise or fall rate	$V_{CC} = 5 \text{ V} \pm 0.5 \text{ V}$		20		20		
T _A	Operating free-air temperature		-55	125	-40	125	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

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The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



7.4 Thermal Information

		SN74AHCT244							
	THERMAL METRIC ⁽¹⁾	C ⁽¹⁾ DB DGV DW N I						UNIT	
		20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	99.9	119.2	83.0	54.9	80.4	105.4		
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	61.7	34.5	48.9	41.7	46.9	39.5		
$R_{\theta JB}$	Junction-to-board thermal resistance	55.2	60.7	50.5	35.8	47.9	56.4	°C/W	
ΨЈТ	Junction-to-top characterization parameter	22.6	1.2	21.1	27.9	19.9	3.1	·C/VV	
ΨЈВ	Junction-to-board characterization parameter	54.8	60.0	50.1	35.7	47.5	55.8		
R ₀ JC(bot)	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	n/a		

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V	T,	λ = 25°C		SN54AH	HC244	SN74AHC244		UNIT
PARAMETER	TEST CONDITIONS	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
V _{OH}		2 V	1.9	2		1.9		1.9		
	I _{OH} = -50 μA	3 V	2.9	3		2.9		2.9		
		4.5 V	4.4	4.5		4.4		4.4		V
	$I_{OH} = -4 \text{ mA}$	3 V	2.58			2.48		2.48		
	$I_{OH} = -8 \text{ mA}$	4.5 V	3.94			3.8		3.8		
		2 V			0.1		0.1		0.1	
	I _{OL} = 50 μA	3 V			0.1		0.1		0.1	
V _{OL}		4.5 V			0.1		0.1		0.1	V
	I _{OL} = 4 mA	3 V			0.36		0.5		0.44	
	I _{OL} = 8 mA	4.5 V			0.36		0.5		0.44	
I _I	V _I = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 ⁽¹⁾		±1	μΑ
I _{OZ}	$V_O = V_{CC}$ or GND, $V_I (\overline{OE}) = V_{IL}$ or V_{IH}	5.5 V			±0.25		±2.5		±2.5	μΑ
I _{CC}	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		40		40	μΑ
C _i	$V_I = V_{CC}$ or GND	5 V		2	10				10	pF
Co	$V_O = V_{CC}$ or GND	5 V	<u>.</u>	3.5						pF

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested at $V_{CC} = 0 \text{ V}$.



7.6 Switching Characteristics

over recommended operating free-air temperature range, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$ (unless otherwise noted) (see Figure 3)

DADAMETED	FROM	то	LOAD	T _A = 25°C		SN54Al	HC244	SN74AH	C244	UNIT			
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII		
t _{PLH}	Α	Y	C ₁ = 15 pF		5.8 ⁽¹⁾	8.4 ⁽¹⁾	1 ⁽¹⁾	10 ⁽¹⁾	1	10	ns		
t _{PHL}	^	Į.	CL = 13 pr		5.8 ⁽¹⁾	8.4 ⁽¹⁾	1 ⁽¹⁾	10 ⁽¹⁾	1	10	115		
t _{PZH}	ŌĒ	Y	C = 15 pE		6.6 ⁽¹⁾	10.6 ⁽¹⁾	1 ⁽¹⁾	12.5 ⁽¹⁾	1	12.5	no		
t _{PZL}	OE	Y	$C_L = 15 pF$		6.6 ⁽¹⁾	10.6 ⁽¹⁾	1 ⁽¹⁾	12.5 ⁽¹⁾	1	12.5	ns		
t _{PHZ}	ŌĒ	Y	C 45 pF		5 ⁽¹⁾	9.7 ⁽¹⁾	1 ⁽¹⁾	11 ⁽¹⁾	1	11			
t _{PLZ}		OE	OE T	Y	$C_L = 15 pF$		5 ⁽¹⁾	9.7 ⁽¹⁾	1 ⁽¹⁾	11 ⁽¹⁾	1	11	ns
t _{PLH}	А	Y	C		8.3	11.9	1	13.5	1	13.5			
t _{PHL}	A	Y	Y	Y	$C_L = 50 \text{ pF}$		8.3	11.9	1	13.5	1	13.5	ns
t _{PZH}	ŌĒ	Y	C		9.1	14.1	1	16	1	16			
t _{PZL}	OE	Y	$C_L = 50 \text{ pF}$		9.1	14.1	1	16	1	16	ns		
t _{PHZ}	ŌĒ	Y	C - 50 pE		10.3	14	1	16	1	16	20		
t _{PLZ}		r	$C_L = 50 \text{ pF}$		10.3	14	1	16	1	16	ns		
t _{sk(o)}			$C_L = 50 pF$	<u> </u>		1.5 ⁽²⁾			·	1.5	ns		

⁽¹⁾ On products compliant to MIL-PRF-38535, this parameter is not production tested.(2) On products compliant to MIL-PRF-38535, this parameter does not apply.

7.7 Switching Characteristics

over recommended operating free-air temperature range, V_{CC} = 5 V ± 0.5 V (unless otherwise noted) (see Figure 3)

	FROM TO LOAD		LOAD	T,	_A = 25°C		SN54Al	HC244	SN74AHC244							
PARAMETER	(INPUT)	(OUTPU T)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT					
t _{PLH}	А	Y	C 45 pF		3.9 ⁽¹⁾	5.5 ⁽¹⁾	1 ⁽¹⁾	6.5 ⁽¹⁾	1	6.5	20					
t _{PHL}	Α	A	r	$C_L = 15 pF$		3.9 ⁽¹⁾	5.5 ⁽¹⁾	1 ⁽¹⁾	6.5 ⁽¹⁾	1	6.5	ns				
t _{PZH}	ŌĒ	Y	C 45 pF		4.7 ⁽¹⁾	7.3 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	20					
t _{PZL}		r	$C_L = 15 pF$		4.7 ⁽¹⁾	7.3 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	ns					
t _{PHZ}	ŌE	Y	C _L = 15 pF		5 ⁽¹⁾	7.2 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	ns					
t _{PLZ}		OE	Į.	O _L = 15 μr		5 ⁽¹⁾	7.2 ⁽¹⁾	1 ⁽¹⁾	8.5 ⁽¹⁾	1	8.5	5 115				
t _{PLH}	Α	Y	C _L = 50 pF		5.4	7.5	1	8.5	1	8.5	ns					
t _{PHL}	Α	ı	C _L = 30 pr		5.4	7.5	1	8.5	1	8.5	115					
t _{PZH}	ŌĒ	Y	C = 50 pE		6.2	9.3	1	10.5	1	10.5	no					
t _{PZL}	OE	ı	$C_L = 50 \text{ pF}$		6.2	9.3	1	10.5	1	10.5	ns					
t _{PHZ}	ŌĒ	Y	C = 50 pE		6.7	9.2	1	10.5	1	10.5	ns					
t _{PLZ}		OE	OE	OE	ī	Y	O _L = 50 pr	C _L = 50 pr	$C_L = 50 \text{ pF}$		6.7	9.2	1	10.5	1	10.5
t _{sk(o)}			$C_L = 50 pF$			1 (2)				1	ns					

On products compliant to MIL-PRF-38535, this parameter is not production tested.

On products compliant to MIL-PRF-38535, this parameter does not apply.



7.8 Noise Characteristics

 $V_{CC} = 5 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C (See}^{(1)})$

	PARAMETER	SN7		LINIT	
	PARAMETER	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.5		V
$V_{OL(V)}$	Quiet output, minimum dynamic V _{OL}		-0.2		V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		4.8		V
$V_{IH(D)}$	High-level dynamic input voltage	3.5			V
$V_{IL(D)}$	Low-level dynamic input voltage			1.5	V

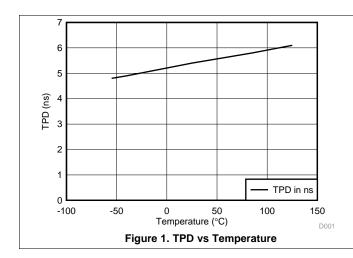
⁽¹⁾ Characteristics are for surface-mount packages only.

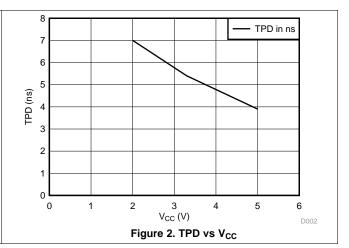
7.9 Operating Characteristics

 $V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd} Power dissipation capacitance	No load, f = 1 MHz	8.6	pF

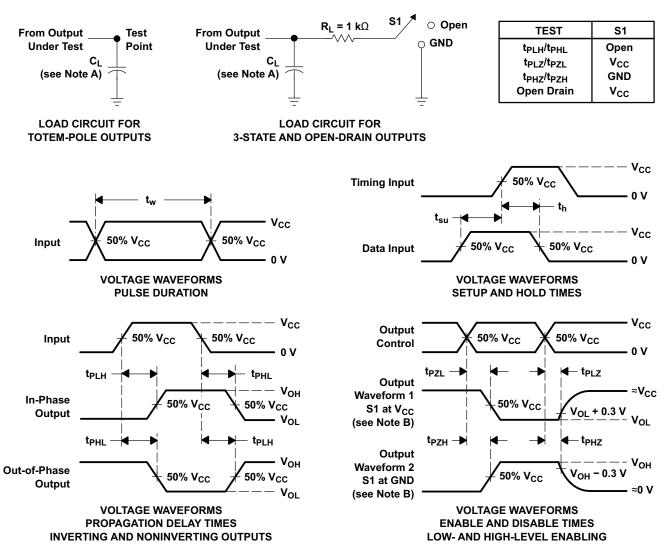
7.10 Typical Characteristics







8 Parameter Measurement Information



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_f \leq 3$ ns, $t_f \leq 3$ ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit and Voltage Waveforms



9 Detailed Description

9.1 Overview

The SNx4AHC244 devices are organized as two 4-bit buffers/line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state. To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

9.2 Functional Block Diagram

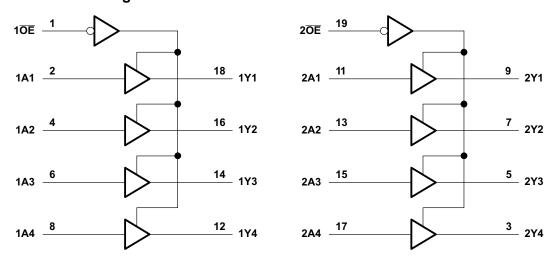


Figure 4. Logic Diagram (Positive Logic)

9.3 Feature Description

- V_{CC} is optimized at 5 V
- Allows down voltage translation
 - Inputs accept V_{IH} levels of 5.5 V
- Slow edge rates minimize output ringing

9.4 Device Functional Modes

Table 1. Function Table (Each 4-Bit Buffer/Driver)

INPL	INPUTS					
ŌĒ	Α	Υ				
L	Н	Н				
L	L	L				
Н	Χ	Z				



10 Application and Implementation

10.1 Application Information

The SNx4AHC244 is a low drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The inputs can except voltages to 5.5 V at any valid V_{CC} making it ideal for down translation.

10.2 Typical Application

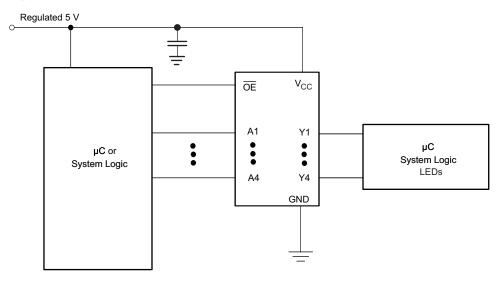


Figure 5. Typical Application Diagram

10.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads so routing and load conditions should be considered to prevent ringing.

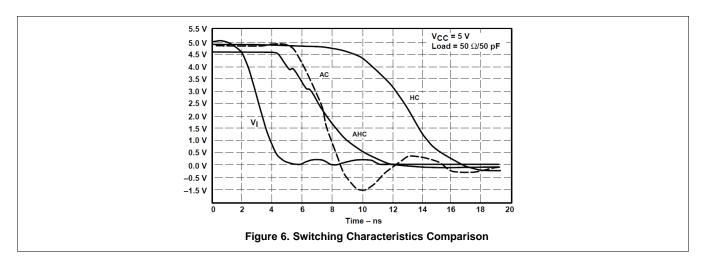
10.2.2 Detailed Design Procedure

- · Recommended input conditions
 - Specified high and low levels. See (V_{IH} and V_{II}) in Recommended Operating Conditions.
 - $-\,$ Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V_{CC}
- Recommend output conditions
 - Load currents should not exceed 25 mA per output and 50 mA total for the part
 - Outputs should not be pulled above V_{CC}



Typical Application (continued)

10.2.3 Application Curves



11 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Recommended Operating Conditions table.

Each VCC pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 µf is recommended; if there are multiple VCC pins, then 0.01 µf or 0.022 µf is recommended for each power pin. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. A 0.1 µf and a 1 µf are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

12 Layout

12.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 7 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or V_{CC} , whichever makes more sense or is more convenient. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the output section of the part when asserted. This will not disable the input section of the I/Os, so they cannot float when disabled.

12.2 Layout Example

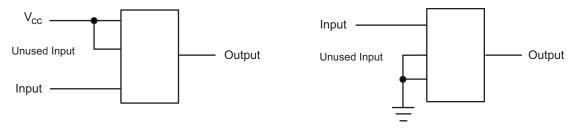


Figure 7. Layout Diagram



13 Device and Documentation Support

13.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54AHC244	Click here	Click here	Click here	Click here	Click here
SN74AHC244	Click here	Click here	Click here	Click here	Click here

13.2 Trademarks

All trademarks are the property of their respective owners.

13.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

13.4 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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11-May-2023 www.ti.com

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9678201Q2A	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9678201Q2A SNJ54AHC 244FK	Samples
5962-9678201QRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9678201QR A SNJ54AHC244J	Samples
5962-9678201QSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9678201QS A SNJ54AHC244W	Samples
5962-9678201VRA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9678201VR A SNV54AHC244J	Samples
5962-9678201VSA	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9678201VS A SNV54AHC244W	Samples
SN74AHC244DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA244	Samples
SN74AHC244DBRE4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA244	Samples
SN74AHC244DGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA244	Samples
SN74AHC244DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC244	Samples
SN74AHC244DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC244	Samples
SN74AHC244N	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHC244N	Samples
SN74AHC244NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHC244	Samples
SN74AHC244PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HA244	Samples
SN74AHC244PWRE4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA244	Samples
SN74AHC244PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HA244	Samples



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Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SNJ54AHC244FK	ACTIVE	LCCC	FK	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9678201Q2A SNJ54AHC 244FK	Samples
SNJ54AHC244J	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9678201QR A SNJ54AHC244J	Samples
SNJ54AHC244W	ACTIVE	CFP	W	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9678201QS A SNJ54AHC244W	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN54AHC244, SN54AHC244-SP, SN74AHC244:

Catalog: SN74AHC244, SN54AHC244

Automotive: SN74AHC244-Q1, SN74AHC244-Q1

● Enhanced Product: SN74AHC244-EP, SN74AHC244-EP

Military: SN54AHC244

Space: SN54AHC244-SP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application



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TAPE AND REEL INFORMATION



TAPE DIMENSIONS KO PI BO Cavity A0

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHC244DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHC244DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHC244DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74AHC244NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHC244PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74AHC244PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHC244PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHC244DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74AHC244DGVR	TVSOP	DGV	20	2000	356.0	356.0	35.0
SN74AHC244DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHC244NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AHC244PWR	TSSOP	PW	20	2000	364.0	364.0	27.0
SN74AHC244PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AHC244PWRG4	TSSOP	PW	20	2000	367.0	367.0	38.0





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TUBE

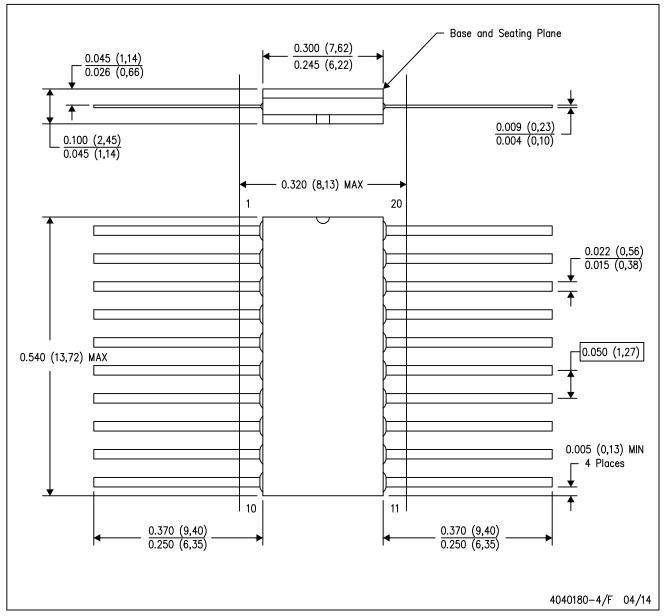


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
5962-9678201Q2A	FK	LCCC	20	1	506.98	12.06	2030	NA
5962-9678201QSA	W	CFP	20	1	506.98	26.16	6220	NA
5962-9678201VSA	W	CFP	20	1	506.98	26.16	6220	NA
SN74AHC244N	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54AHC244FK	FK	LCCC	20	1	506.98	12.06	2030	NA
SNJ54AHC244W	W	CFP	20	1	506.98	26.16	6220	NA

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within Mil-Std 1835 GDFP2-F20







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



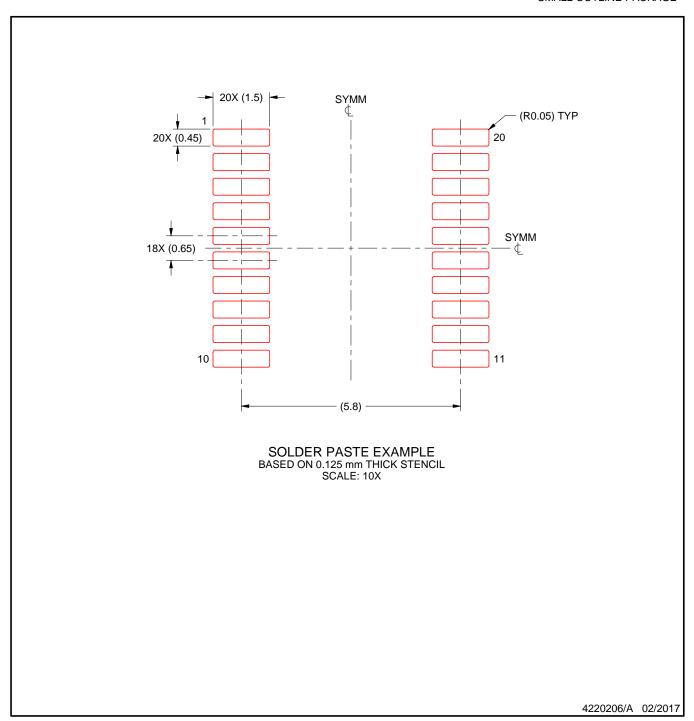


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





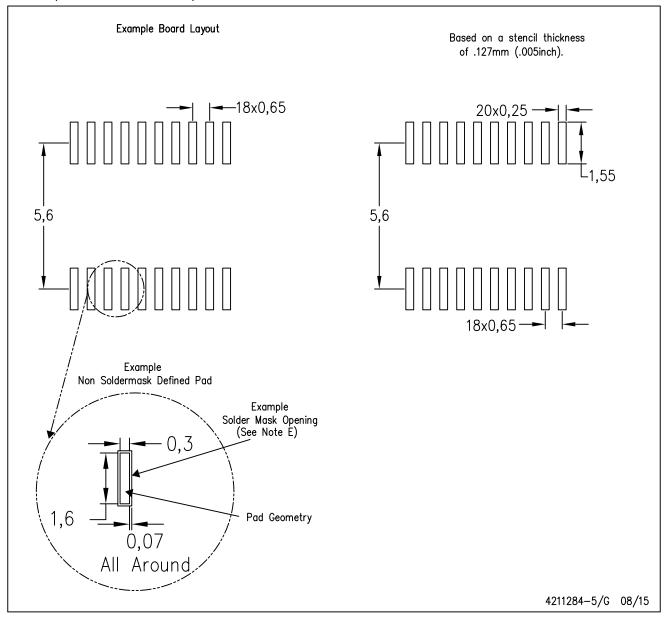
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

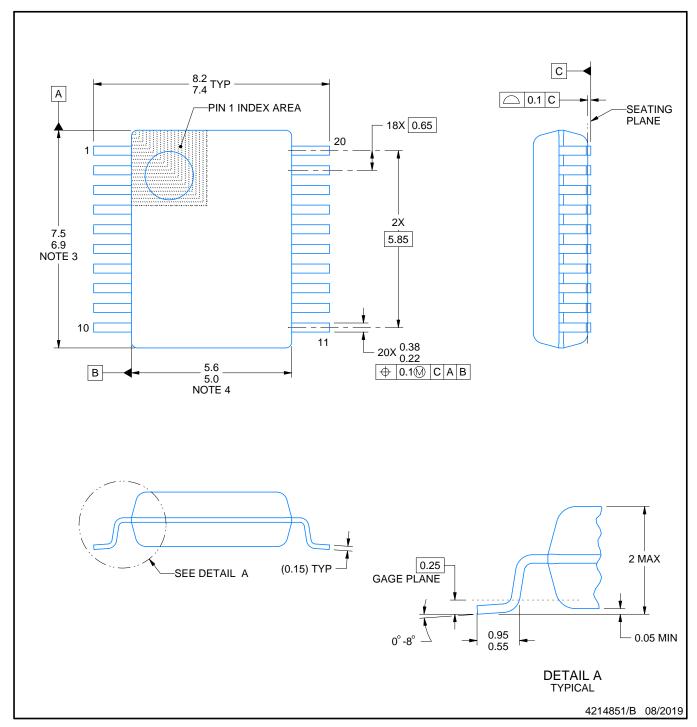
PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



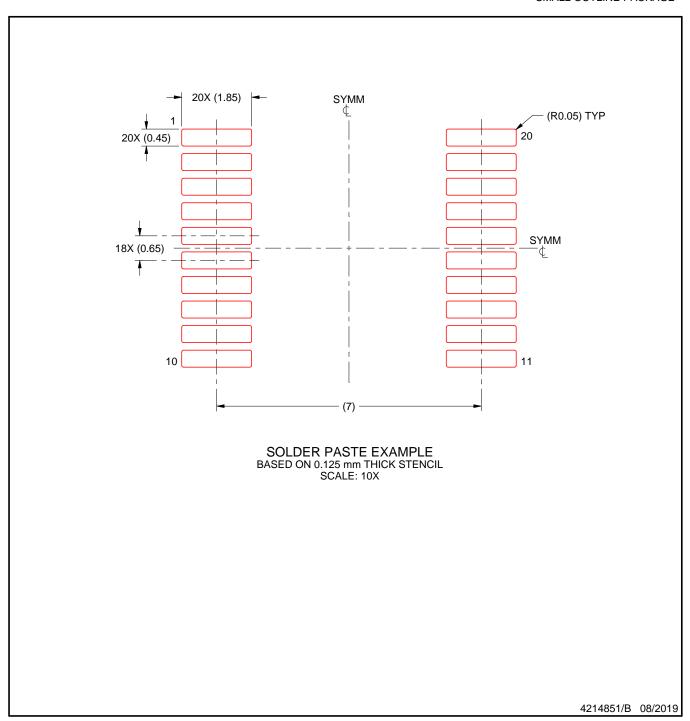


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.

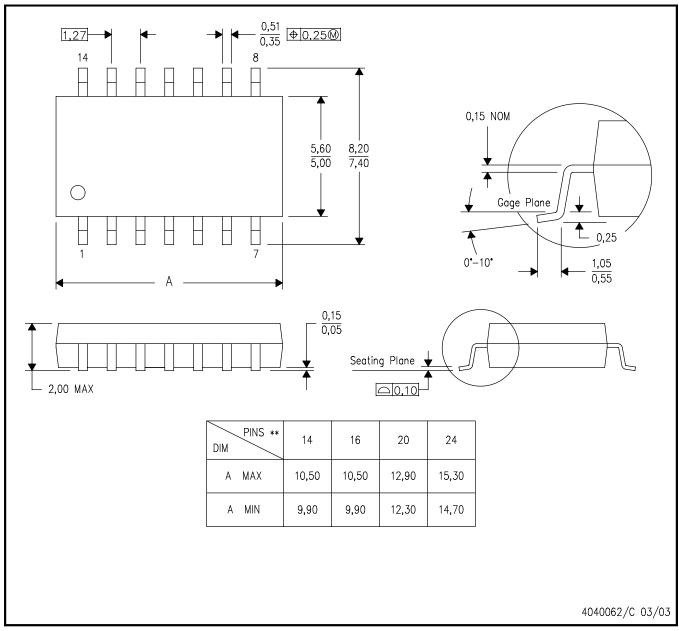


MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

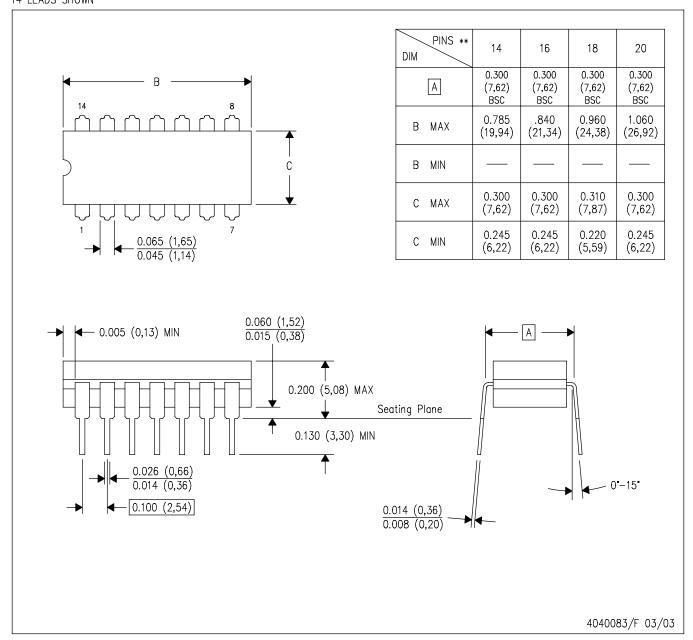
PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

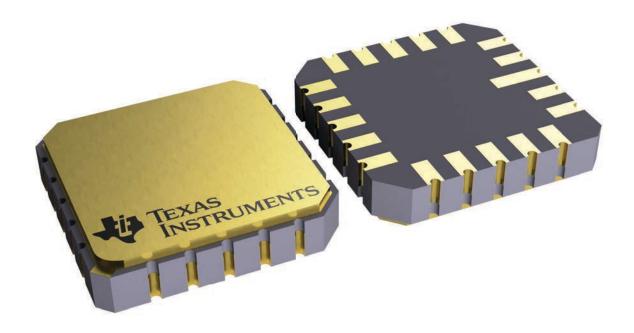
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194 8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

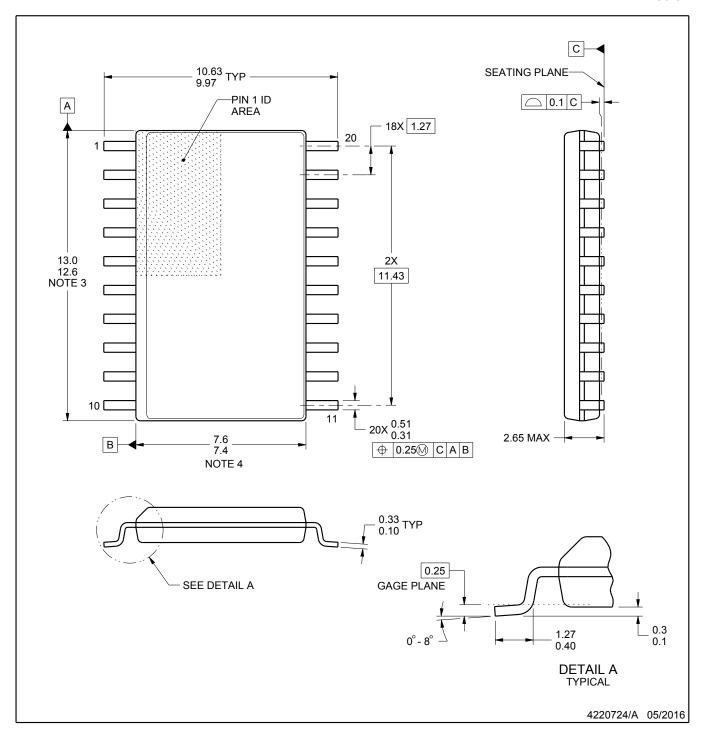


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



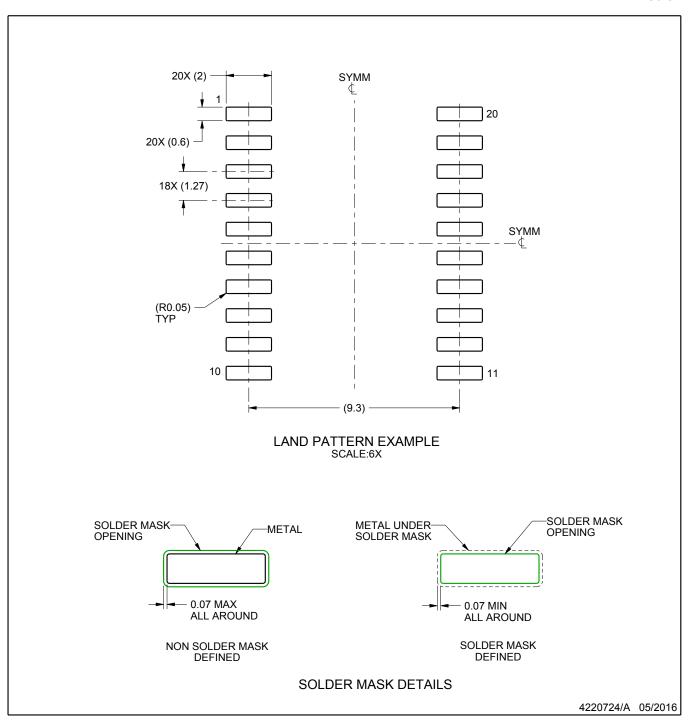
- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC

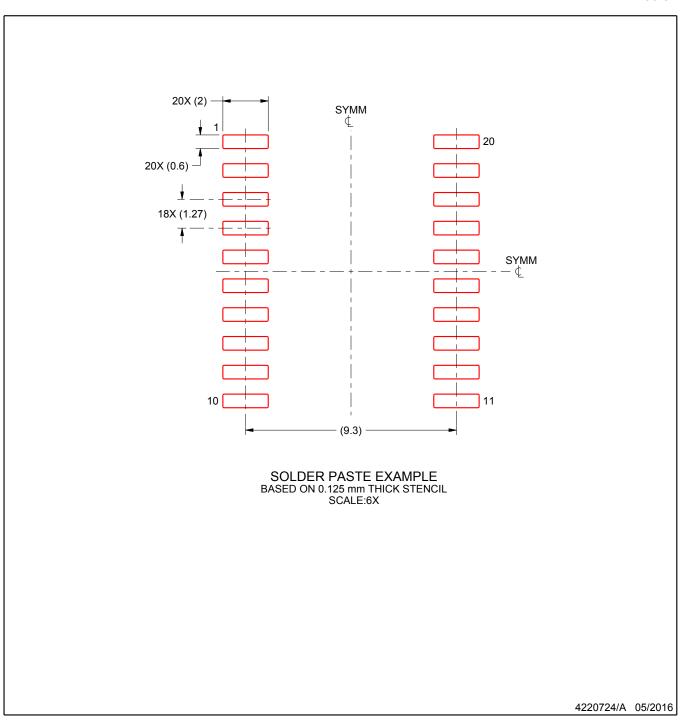


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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